

Influence of the presence of deuterium on displacement damage in tungsten

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Theoretical predictions

- 'DFT molecular dynamics revealed that hydrogen clusters can prevent a vacancy from recombining with the neighboring crowdion-type self-interstitial-atom.'
 D. Kato et al., Nucl. Fusion 55 (2015) 083019
- 'Atomic scale computer simulations have predicted a decrease in the W vacancy formation energy in the presence of H ... Findings of this work suggest that H not only promotes vacancy formation in W, but once formed the vacancy will also initiate further H clustering' S.C. Middleburgh, J. Nucl. Mater. 448 (2014) 270



Motivation





14 MeV n



In present day lab experiments:



⇒ mutual influence of D on damage creation/evolution?

Experimental strategy



Shown before by Sabina:



Experimental strategy



Approach here: sequential treatment multiple times



Experimental strategy



- Compare D retention in
 - tungsten free of D
 - tungsten 'saturated with D'

after 20 MeV W bombardment and D decoration of defects

- \Rightarrow Questions to address beforehand:
 - D uptake as function of W damaging fluence (Does damage saturate?)
 - D uptake as function of D fluence (How to <u>decorate</u> defects without creating new ones?)

Outline



- Motivation
- D retention in self-damaged tungsten
- Multiple sequence experiments: Damage creation D loading
 D depth profiles and thermal desorption data
- Present rate equation modelling approaches

A comment before I start



- High energy and/or high flux D (plasma) exposure leads to
 - H oversaturation

[L.Gao et al., Nucl. Fusion 2017 https://doi.org/10.1088/0029-5515/57/1/016026]

- damage creation (point defects ... blisters)

which we want to avoid in this study (not trivial, see e.g. S. Kapser et al., Nucl. Fusion, 2018 <u>http://dx.doi.org/10.1088/1741-4326/aab571</u>)

 The strategy here is to investigate the effect of displacement damage, hence D loading needs to be done <u>without creating new damage</u>

D decoration: gentle plasma exposure



known flux and energy

- energy: "<5 eV/D" (floating targets)
- ion flux: 6 ×10¹⁹ D/(m²s)

(97% as D_3^+ , 2% as D_2^+ , 1% as D^+)

- atom flux > $10^{21} D^{0/(m^2s)}$
- ion fluence: up to 5.10²⁴ D/m² per day
- 'gentle' loading = 'decoration':
 T = 370 K
 - no additional defect creation
 - no defect evolution/annealing)
- six samples simultaneously



A. Manhard, Plasma Sources Sci. Technol. 20 (2011) 015010

The tungsten substrate material



confocal scanning laser microscopy



- Plansee AG hot-rolled tungsten, purity 99.97 wt.-%
- chemo-mechanically polished to mirror finish [1]
- annealed at 2000 K for 2 min at p < 5 ×10⁻⁸ mbar to reduce initial defect density
- to 2×10¹² m/m³ [2]

[1] A. Manhard et al., Pract. Metallogr. 50 (1) (2013) 6–15.[2] A. Manhard et al., Pract. Metallorg. 52 (2015) 437.

Creating displacement damage: W self-implantation



- 14 MeV fusion neutrons will cause
 - transmutation
 - gas production
 - displacement damage ($E_{pka} < 200 \text{ keV}$)
- Here: only displacement damage aspect is studied with W self-implantation



Creating displacement damage: W self-implantation





- 300 keV W would reduce information depth to 30 nm : Too little material for diagnostics (nuclear reaction analysis, thermal desorption spectroscopy)
- Cascade splitting makes it still relevant (?)
 [A. Sand et al. *Mater. Res. Lett.* 5 (5), 357–63 (2017)]



Previous investigation:

- fluence series 20 MeV W⁶⁺ @ 290 K
- D decoration with < 5 eV/D for 72 h (1.5 ×10²⁵ D/m²) @ 450 K
- D/W > 1 at.% @ 0.23 dpa



depth (µm)





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- linear increase for < 0.005 dpa
- saturation in D for > 0.23 dpa





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Saturating displacement damage with D





This study:

- D decoration @ 370 K
- 2 times 1.5·10²⁵ D/m² (2 x 72 h)
- check if damaged zone is completely filled with D

 \Rightarrow It is, up to **1.7 at.%**







- beam sweep for laterally homogenous damage
- accuracy, reproducibility:

better than 5%

 \Rightarrow box like D reservoir



Displacements during 20 MeV W



SDTrimSP calculation:

- 20 MeV W on W, containing 2 % D
- $\Phi = 7.87 \times 10^{17} \text{ W}^{6+}/\text{m}^2$
- displacement energy
 - $E_{displ. W}$ = 90 eV, $E_{cutoff, W}$ = 2.2 eV

-
$$E_{displ, D} = 1 \text{ eV}, E_{cutoff, D} = 0.25 \text{ eV}$$

- \Rightarrow tungsten atoms are displaced and defects are generated (0.23 dpa)
- ⇒ simultaneously, retained deuterium atoms (1.7%!) are de-trapped in the vicinity of the displacement damage: kinetic detrapping



D depth profiles





depth (μ m)

D depth profiles





What happens to the initially retained D?

 \Rightarrow no change in depth profile

⇒ D gets efficiently re-trapped during W implantation



D effusion during thermal desorption





What happens to the D binding?



D effusion during thermal desorption





What happens to the D binding?

 \Rightarrow shift of desorption to larger desorption energies!

 \Rightarrow new trap types?



D depth profiles





Decoration after 2nd damaging:

⇒ D retention increases to 2.8 at.% (!) exceeding D at. fraction by ≈ factor 2 beyond previous 'saturation value'!



 \Rightarrow new trap types now filled?

Thermal desorption spectroscopy





Decoration after 2nd damaging:

- ⇒ TDS spectra resembles again the spectrum of the initially decorated, singly damaged W!
- \Rightarrow only larger intensity

 \Rightarrow same trap types?



Artefact from surface blisters?



Suspicion:

- increased retention due to surface blisters? (unlikely giving the same depth profile)
- 30 SEM micrographs (30 µm in size) show no indication on gas filled cavities
- in line with dedicated studies such as a S. Kapser et al., Nucl. Fusion
- in line with lack of D₂ bursts in TDS spectra

SE images









TESSIM-X code with fill-level-dependent trapping [K. Schmid et al. JAP 116, 134901 (2014)]

- creation of additional empty traps (by a factor of 1.7 during 2nd W implantation) explains temperature shift!
- TDS spectra with and without kinetic de-trapping indistinguishable





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See: T. Schwarz-Selinger et al. *Nucl. Mater. Energy* 17 (2017): 228–34. <u>https://doi.org/10.1016/j.nme.2018.10.005</u>.

Triple damaging



- Did we reach with 2.8 at. % the maximum D concentration?
- Triple damaging



• ⇒ 3.6 at. %



Triple damaging



- Did we reach with 2.8 at. % the maximum D concentration?
- Triple damaging







Damage stabilization model:

- $n_i(x, t)$: density of defect type *i*.
- Γ_W : flux of damaging W particles,
- $\Theta(x)$: SRIM calculated primary damage profile
- η : probability of an impinging W particle to create a defect per unit length ρ : density of tungsten
- n_i^0 : density of empty defects of type *i*
- Free parameters of the model
- $n_{i,max}$: saturation density of defect type *i*,
- α_i : stabilization parameter for defect type *i*.

[M. Pečovnik et al. submitted to Nucl. Fusion]

ratio of D occupied defects of type *i*

 $\frac{dn_i(x,t)}{dt} = \frac{\Gamma_W \eta \theta(x)}{\rho} \left[1 - \frac{n_i(x,t)}{n_i \max} \left(1 - \alpha_i \frac{n_i(x,t) - n_i^0(x,t)}{n_i(x,t)} \right) \right]$

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- defect type I: n_{max} = 0.21 at.% fill level energies: 1.07 eV, 1.15 eV, 1.23 eV, 1.33 eV, 1.43 eV,
- defect type II: n_{max} = 0.29 at.% fill level energies: 1.66 eV, 1.84 eV,
- defect type III: n_{max} = 0.04 at.% fill level energy: 2.06 eV.



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- Fill levels: $N_1^{\text{fill}} = 5$, $N_2^{\text{fill}} = 2$



Present interpretation

Different saturation/defect levels:

- D free W: saturation in n_{Dmax} = 1.7 at.% above 0.2 dpa because
 Frenkel pairs can annihilate with existing ones
- D filled W: n_{Dmax} = 4.2 at.% because newly created defects cannot annihilate with existing ones when they are occupied by D: stabilization







Summary



Influence of the presence of D on displacement damage

- <u>Multiple</u> sequences of <u>creating displacement damage</u> and <u>decorating defects</u> <u>with D</u> allows to study the influence of D on damage creation/stabilization (even at low temperatures) without the need for a dual beam in-situ setup
- D retention exceeds the initial 'saturation value' by more than a factor of two (at 290 K damaging) n_D = 1.7 at.% ⇒ 2.8 at.% ⇒ 3.6 at.% ⇒ ... 4.x at.%
- No D is lost during consecutive W implantations / D is de-trapped but is effectively re-trapped
- D is redistributed from the low temperature de-trapping peak to the high temperature de-trapping peak (during W irradiation or during TDS)
- TDS shows no indication for new defect nature but only increased density
- Rate equation modelling successful with increased defect density only
- Damage stabilization model describes observation successfully

Backup slides

Related MD modelling



F. J. Dominguez-Gutierrez and U. von Toussaint

- Simulating the cascade core by heating to 10000 K for 5 ps (using a Langevin thermostat) to emulate the core region of a collision cascade with and without D present (work in progress)
- Using descriptor based method [*F. J. Dominguez-Gutierrez and U. von Toussaint, submitted to J. Nucl. Mater*] to identify defects created (IAEA challenge winner)



Potential diagram





Tetrahedral sites in



bcc lattice

Potential diagram





Parameters for W

½ E_{diss}= 2.25 eV E_{ch}=0.5 – 0.8 eV Q_{Sol}=1.04 eV

Two populations:

 $\Delta E_{D} = 0.39 \text{ eV}$ (better 0.25 eV?)

 $\Delta E_{trap} \approx 0.8 - 2 \text{ eV}$

Defect evolution during gentle loading



D retention in W foils after 192 h plasma exposure (fluence ≈ 4·10²⁵ D/m²)
 S. Kapser et al., Nucl. Fusion, 2018 <u>http://dx.doi.org/10.1088/1741-4326/aab571</u>)

